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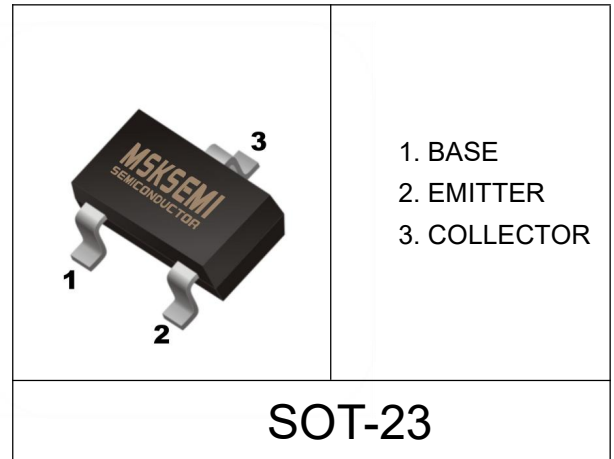
PLED

BC817-16/25/40

Product specification

FEATURES

- For general AF applications
- High collector current
- High current gain
- Low collector-emitter saturation voltage
- Complementary types: BC807 (PNP)



CLASSIFICATION OF $h_{FE(1)}$

Rank	BC817-16	BC817-25	BC817-40
Range	100-250	160-400	250-600
Marking	6A	6B	6C

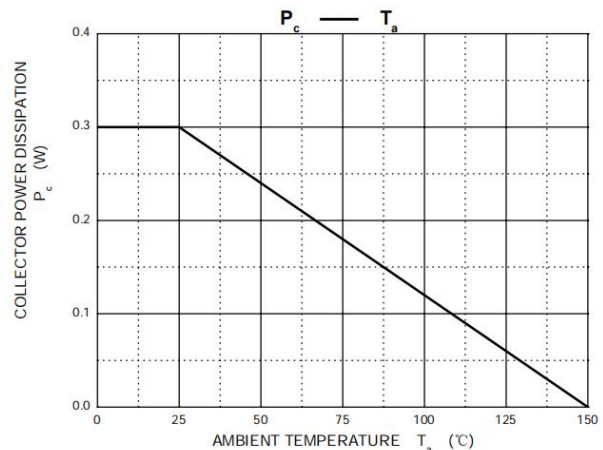
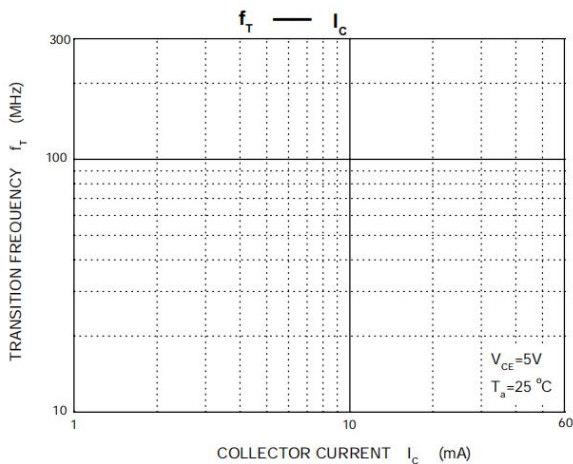
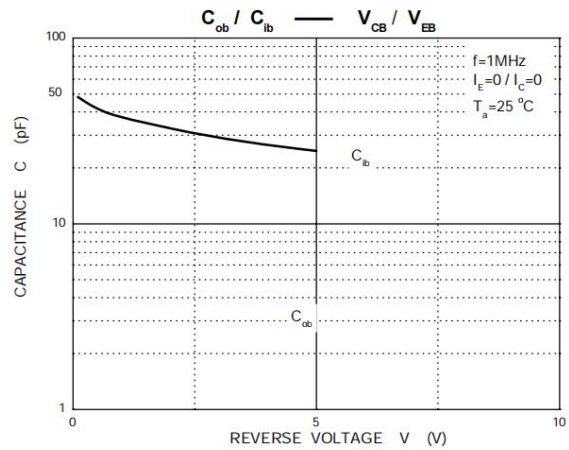
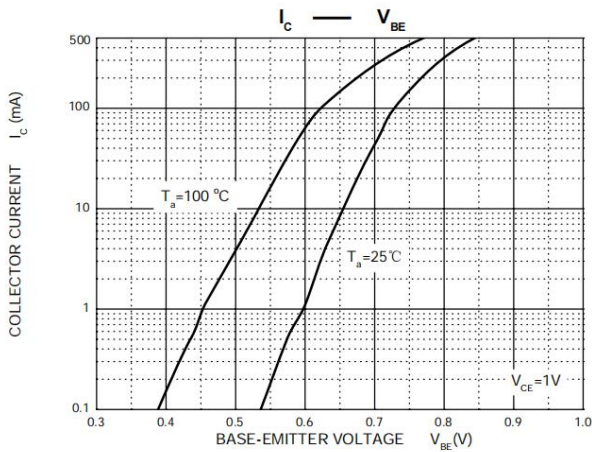
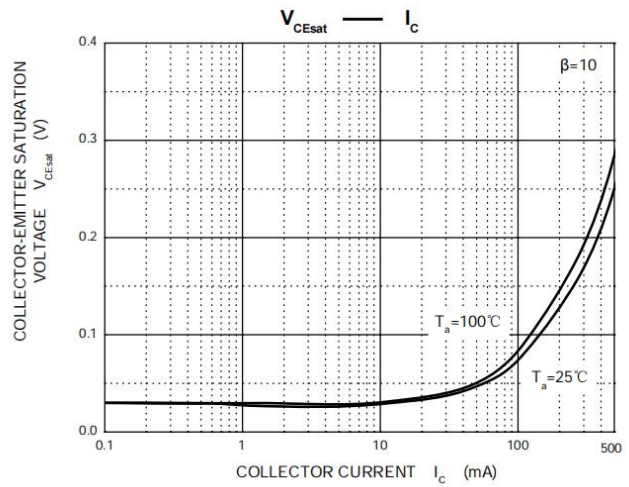
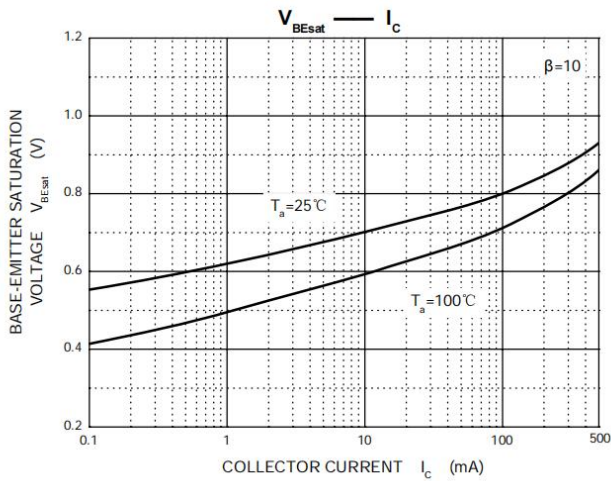
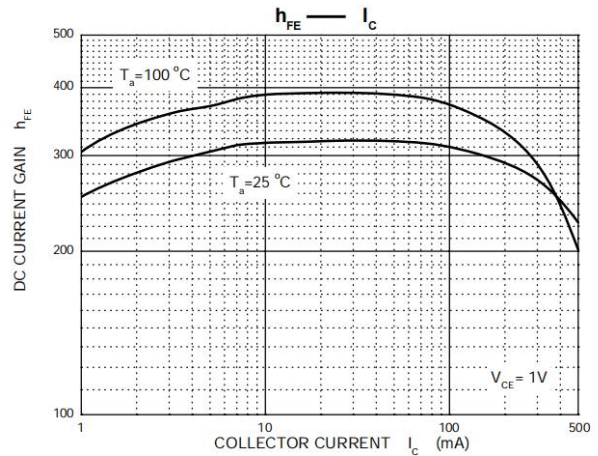
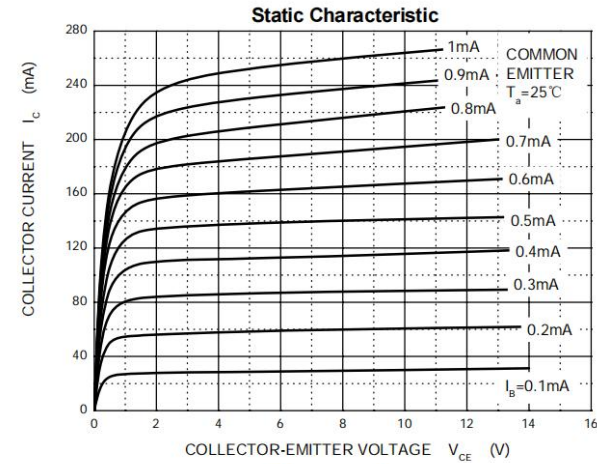
MAXIMUM RATINGS (Ta=25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
V _{CB0}	Collector-Base Voltage	50	V
V _{CEO}	Collector-Emitter Voltage	45	V
V _{EB0}	Emitter-Base Voltage	5	V
I _C	Collector Current	500	mA
P _C	Collector Power Dissipation	300	mW
R _{θJA}	Thermal Resistance From Junction To Ambient	417	°C/W
T _J , T _{stg}	Operation Junction and Storage Temperature Range	-55~+150	°C

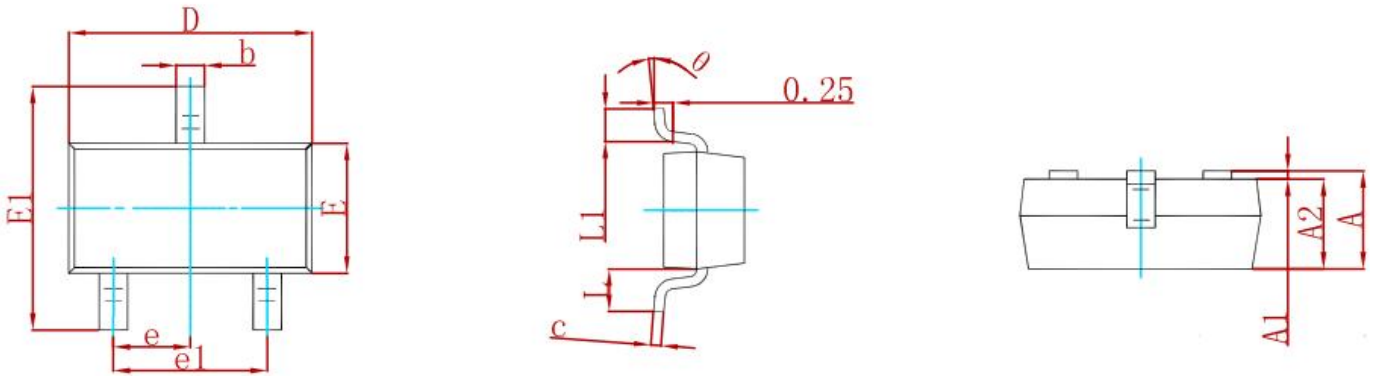
ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V _{CB0}	I _C = 10pA, I _E =0	50			V
Collector-emitter breakdown voltage	V _{CEO}	I _C = 10mA, I _B =0	45			V
Emitter-base breakdown voltage	V _{EB0}	I _E = 1pA, I _C =0	5			V
Collector cut-off current	I _{CB0}	V _{CB} = 45 V, I _E =0			0.1	uA
Emitter cut-off current	I _{EB0}	V _{EB} = 4V, I _C =0			0.1	uA
DC current gain	FE(1)	V _{CE} = 1V, I _C = 100mA	100		600	
	FE(2)	V _{CE} = 1V, I _C = 500mA	40			
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = 500mA, I _B = 50mA			0.7	V
Base-emitter saturation voltage	V _{BE(sat)}	I _C = 500mA, I _B = 50mA			1.2	V
Base-emitter voltage	V _{BE}	V _{CE} = 1 V, I _C = 500mA			1.2	V
Collector capacitance	C _{ob}	V _{CB} =10V, f=1MHz		10		pF
Transition frequency	f _T	V _{CE} = 5 V, I _C = 10mA f=100MHz	100			MHz

Typical Characteristics

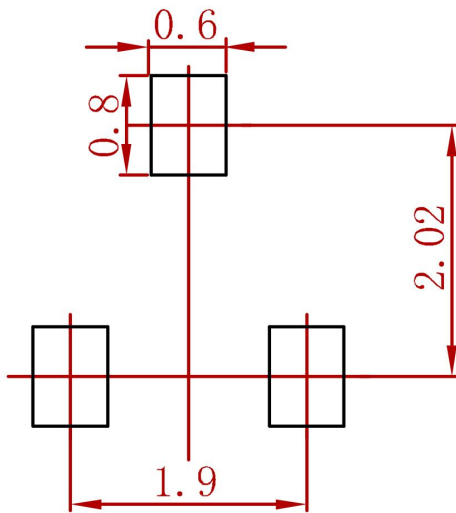


PACKAGE MECHANICAL DATA



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: ±0.05mm.
3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY
BC817-16/25/40	SOT-23	3000

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